

Wei Liu

List of Publications by Year in descending order

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54
papers

3,919
citations

236925

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h-index

168389

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all docs

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docs citations

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times ranked

2816
citing authors

#	ARTICLE	IF	CITATIONS
1	Convergence of Conduction Bands as a Means of Enhancing Thermoelectric Performance of $Mg_{2-x}Si_{x-0.5}Sn_{0.5}Sb_y$. <i>Journal of Applied Physics</i> , 2018, 123, 155101.	7.8	1,048
2	Rhombohedral to Cubic Conversion of GeTe via MnTe Alloying Leads to Ultralow Thermal Conductivity, Electronic Band Convergence, and High Thermoelectric Performance. <i>Journal of the American Chemical Society</i> , 2018, 140, 2673-2686.	13.7	307
3	Power generation and thermoelectric cooling enabled by momentum and energy multiband alignments. <i>Science</i> , 2021, 373, 556-561.	12.6	270
4	High thermoelectric performance in $Bi_{0.46}Sb_{1.54}Te_3$ nanostructured with ZnTe. <i>Energy and Environmental Science</i> , 2018, 11, 1520-1535.	30.8	239
5	Multi-Scale Microstructural Thermoelectric Materials: Transport Behavior, Non-Equilibrium Preparation, and Applications. <i>Advanced Materials</i> , 2017, 29, 1602013.	21.0	234
6	Optimized Thermoelectric Properties of Sb-Doped $Mg_{2-x}Si_{x-0.5}Sn_{0.5}Sb_y$ through Adjustment of the Mg Content. <i>Chemistry of Materials</i> , 2011, 23, 5256-5263.	6.7	148
7	Thermal conductivity in $Bi_{0.5}Sb_{1.5}Te_{3+x}$ and the role of dense dislocation arrays at grain boundaries. <i>Science Advances</i> , 2018, 4, eaar5606.	10.3	143
8	High thermoelectric performance of p-BiSbTe compounds prepared by ultra-fast thermally induced reaction. <i>Energy and Environmental Science</i> , 2017, 10, 2638-2652.	30.8	138
9	A comprehensive review on Bi_2Te_3 -based thin films: Thermoelectrics and beyond. <i>Journal of Applied Physics</i> , 2022, 1, 88-115.		119
10	Advanced thermoelectrics governed by a single parabolic band: $Mg_{2-x}Si_{x-0.3}Sn_{0.7}$, a canonical example. <i>Physical Chemistry Chemical Physics</i> , 2014, 16, 6893-6897.	2.8	114
11	Rapid preparation of $CeFe_4Sb_{12}$ skutterudite by melt spinning: rich nanostructures and high thermoelectric performance. <i>Journal of Materials Chemistry A</i> , 2013, 1, 12657.	10.3	101
12	Discordant nature of Cd in GeTe enhances phonon scattering and improves band convergence for high thermoelectric performance. <i>Journal of Materials Chemistry A</i> , 2020, 8, 1193-1204.	10.3	83
13	Low effective mass and carrier concentration optimization for high performance p-type $Mg_{2-x}Li_{2x}Si_{x-0.3}Sn_{0.7}$ solid solutions. <i>Physical Chemistry Chemical Physics</i> , 2014, 16, 23576-23583.	2.8	77
14	Eco-friendly high-performance silicide thermoelectric materials. <i>National Science Review</i> , 2017, 4, 611-626.	9.5	71
15	Large Thermal Conductivity Drops in the Diamondoid Lattice of $CuFeS_2$ by Discordant Atom Doping. <i>Journal of the American Chemical Society</i> , 2019, 141, 18900-18909.	13.7	66
16	Understanding the combustion process for the synthesis of mechanically robust SnSe thermoelectrics. <i>Nano Energy</i> , 2018, 44, 53-62.	16.0	51
17	Realization of non-equilibrium process for high thermoelectric performance Sb-doped GeTe. <i>Science Bulletin</i> , 2018, 63, 717-725.	9.0	49
18	Realization of high thermoelectric performance in p-type unfilled ternary skutterudites $FeSb_{2+x}Te_{1-x}$ via band structure modification and significant point defect scattering. <i>Acta Materialia</i> , 2013, 61, 7693-7704.	7.9	44

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19	Nonmagnetic In Substituted CuFe _{1-x} In _x S ₂ Solid Solution Thermoelectric. Journal of Physical Chemistry C, 2016, 120, 27895-27902.	3.1	42
20	Modification of Bulk Heterojunction and Cl Doping for High-Performance Thermoelectric SnSe ₂ /SnSe Nanocomposites. ACS Applied Materials & Interfaces, 2018, 10, 15793-15802.	8.0	39
21	Thermoelectric performance of CuFeS _{2+2x} composites prepared by rapid thermal explosion. NPG Asia Materials, 2017, 9, e390-e390.	7.9	38
22	Identifying the Manipulation of Individual Atomic-Scale Defects for Boosting Thermoelectric Performances in Artificially Controlled Bi ₂ Te ₃ Films. ACS Nano, 2021, 15, 5706-5714.	14.6	38
23	Realizing High Thermoelectric Performance in Sb-Doped Ag ₂ Te Compounds with a Low-Temperature Monoclinic Structure. ACS Applied Materials & Interfaces, 2020, 12, 39425-39433.	8.0	35
24	Enhancing Thermoelectric Performance of n-Type PbSe through Forming Solid Solution with PbTe and PbS. ACS Applied Energy Materials, 2020, 3, 2-8.	5.1	27
25	Thermoelectric transport properties of p-type silver-doped PbS with <i>in situ</i> Ag ₂ S nanoprecipitates. Journal Physics D: Applied Physics, 2014, 47, 115303.	2.8	26
26	Interpreting the Combustion Process for High-Performance ZrNiSn Thermoelectric Materials. ACS Applied Materials & Interfaces, 2018, 10, 864-872.	8.0	26
27	Anomalous Large Seebeck Coefficient of CuFeS ₂ Derives from Large Asymmetry in the Energy Dependence of Carrier Relaxation Time. Chemistry of Materials, 2020, 32, 2639-2646.	6.7	26
28	Low temperature thermoelectric properties of <i>p</i> -type doped single-crystalline SnSe. Applied Physics Letters, 2018, 112, .	3.3	24
29	Electron Density Optimization and the Anisotropic Thermoelectric Properties of Ti Self-Intercalated Ti _{1+x} S ₂ Compounds. ACS Applied Materials & Interfaces, 2018, 10, 32344-32354.	8.0	23
30	Ultrafast Synthesis and Thermoelectric Properties of Mn _{1+x} Te Compounds. ACS Applied Materials & Interfaces, 2018, 10, 25519-25528.	8.0	22
31	Optimizing the average power factor of p-type (Na, Ag) co-doped polycrystalline SnSe. RSC Advances, 2019, 9, 7115-7122.	3.6	20
32	Thickness-dependent electronic transport induced by <i>in situ</i> transformation of point defects in MBE-grown Bi ₂ Te ₃ thin films. Applied Physics Letters, 2020, 117, .	3.3	19
33	Enhanced Thermoelectric Properties of Codoped Cr ₂ Se ₃ : The Distinct Roles of Transition Metals and S. ACS Applied Materials & Interfaces, 2018, 10, 22389-22400.	8.0	18
34	Bridging the miscibility gap towards higher thermoelectric performance of PbS. Acta Materialia, 2021, 220, 117337.	7.9	17
35	Rationally optimized carrier effective mass and carrier density leads to high average <i>ZT</i> value in n-type PbSe. Journal of Materials Chemistry A, 2021, 9, 23011-23018.	10.3	15
36	Structure and thermoelectric properties of 2D Cr ₂ Se ₃ ^{3x} S _{3x} solid solutions. Journal of Materials Chemistry C, 2018, 6, 836-846.	5.5	13

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37	Fine-tuning the solid-state ordering and thermoelectric performance of regioregular P3HT analogues by sequential oxygen-substitution of carbon atoms along the alkyl side chains. <i>Journal of Materials Chemistry C</i> , 2019, 7, 2333-2344.	5.5	13
38	Weyl Semimetal States Generated Extraordinary Quasi-Linear Magnetoresistance and Nernst Thermoelectric Power Factor in Polycrystalline NbP. <i>Advanced Functional Materials</i> , 2022, 32, .	14.9	13
39	Enhanced Mechanical Properties of Na _{0.02} Pb _{0.98} Te/MoTe ₂ Thermoelectric Composites Through in-Situ-Formed MoTe ₂ . <i>ACS Applied Materials & Interfaces</i> , 2019, 11, 41472-41481.	8.0	12
40	Identifying the Origins of High Thermoelectric Performance in Group IIIA Element Doped PbS. <i>ACS Applied Materials & Interfaces</i> , 2020, 12, 14203-14212.	8.0	12
41	Self-propagating high-temperature synthesis and thermoelectric performances of Cu ₂ SnSe ₃ . <i>Journal of Alloys and Compounds</i> , 2018, 750, 965-971.	5.5	11
42	Impurity states in Mo _{1-x} M _x Se ₂ compounds doped with group VB elements and their electronic and thermal transport properties. <i>Journal of Materials Chemistry C</i> , 2020, 8, 619-629.	5.5	11
43	Epitaxial growth and improved electronic properties of (Bi _{1-x} Sb _x) ₂ Te ₃ thin films grown on sapphire (0001) substrates: The influence of Sb content and the annealing. <i>Journal of Alloys and Compounds</i> , 2015, 647, 50-56.	5.5	10
44	Synergistically Improved Electronic and Thermal Transport Properties in Nb-Doped Nb _{1-y} Mo _{1-x} Se ₂ Te _{2-x} Solid Solutions Due to Alloy Phonon Scattering and Increased Valley Degeneracy. <i>ACS Applied Materials & Interfaces</i> , 2019, 11, 26069-26081.	8.0	9
45	One-step ultra-rapid fabrication and thermoelectric properties of Cu ₂ Se bulk thermoelectric material. <i>RSC Advances</i> , 2019, 9, 10508-10519.	3.6	9
46	Synergistically Enhanced Thermoelectric Performance of Cu ₂ SnSe ₃ -Based Composites via Ag Doping Balance. <i>ACS Applied Materials & Interfaces</i> , 2021, 13, 55178-55187.	8.0	9
47	Origins of enhanced thermoelectric power factor in topologically insulating Bi _{0.64} Sb _{1.36} Te ₃ thin films. <i>Applied Physics Letters</i> , 2016, 108, .	3.3	8
48	Tendency of Gap Opening in Semimetal 1T-MoTe ₂ with Proximity to a 3D Topological Insulator. <i>Advanced Functional Materials</i> , 2021, 31, 2103384.	14.9	8
49	Enhanced Thermoelectric Properties of Cu ₂ SnSe ₃ -Based Materials with Ag ₂ Se Addition. <i>ACS Applied Materials & Interfaces</i> , 2022, 14, 5439-5446.	8.0	7
50	Structure and Improved Thermoelectric Properties of Ag _{2-x} Cr _{2-x} Se ₃ Compounds. <i>Inorganic Chemistry</i> , 2018, 57, 12125-12131.	4.0	5
51	Evolution of atomic structure and electronic transport properties in n-type Bi ₂ Te ₃ films via Bi ₂ planar defects. <i>Applied Physics Letters</i> , 2021, 118, 103901.	3.3	4
52	Strong Anisotropy and Bipolar Conduction-Dominated Thermoelectric Transport Properties in the Polycrystalline Topological Phase of ZrTe ₅ . <i>Inorganic Chemistry</i> , 2021, 60, 8890-8897.	4.0	4
53	High band degeneracy and weak chemical bonds leading to enhanced thermoelectric transport properties in 2H-MoTe ₂ . <i>Journal of Solid State Chemistry</i> , 2021, 300, 122227.	2.9	2
54	Native Atomic Defects Manipulation for Enhancing the Electronic Transport Properties of Epitaxial SnTe Films. <i>ACS Applied Materials & Interfaces</i> , 2021, 13, 56446-56455.	8.0	2